

## HIGH EFFICIENCY RECTIFIER

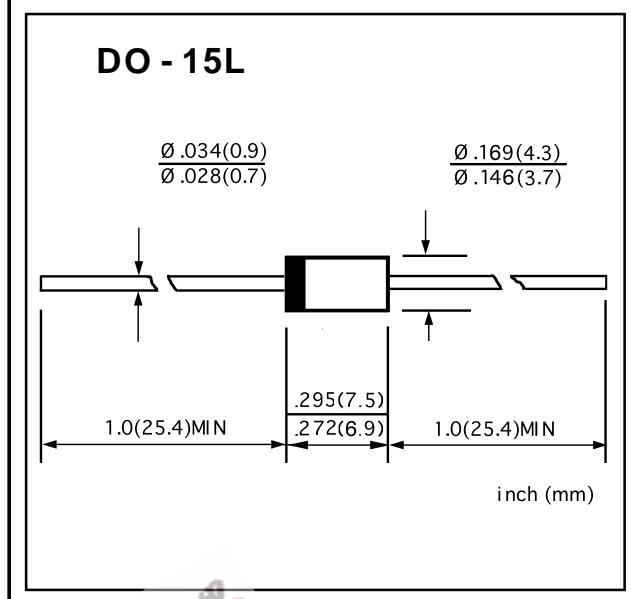
VOLTAGE RANGE: 400 --- 600 V  
CURRENT: 1.1 A

### FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropanol and similar solvents

### MECHANICAL DATA

- ◇ Case: JEDEC DO-15L, molded plastic
- ◇ Terminals: Axial leads, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.017 ounces, 0.48 grams
- ◇ Mounting: Any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 50 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		RU2M	RU2AM	UNITS
Maximum peak repetitive reverse voltage	$V_{RRM}$	400	600	V
Maximum RMS voltage	$V_{RMS}$	280	420	V
Maximum DC blocking voltage	$V_{DC}$	400	600	V
Maximum average forward rectified current 9.5mm lead length, @ $T_A=75^\circ\text{C}$	$I_{F(AV)}$	1.1		A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ\text{C}$	$I_{FSM}$	20.0		A
Maximum instantaneous forward voltage @ 1.1A	$V_F$	1.2		V
Maximum reverse current @ $T_A=25^\circ\text{C}$ at rated DC blocking voltage @ $T_A=100^\circ\text{C}$	$I_R$	10.0 300.0		$\mu\text{A}$
Maximum reverse recovery time (Note 1)	$t_{rr}$	100		ns
Typical junction capacitance (Note 2)	$C_J$	20	15	pF
Typical thermal resistance (Note 3)	$R_{\theta JL}$	15		$^\circ\text{C}/\text{W}$
Operating junction temperature range	$T_J$	- 55 ----- + 150		$^\circ\text{C}$
Storage temperature range	$T_{STG}$	- 55 ----- + 150		$^\circ\text{C}$

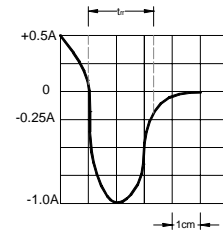
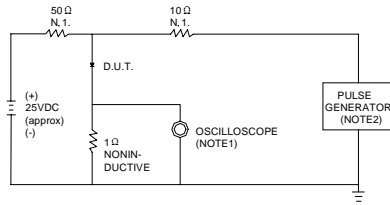
NOTE: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient.

www.galaxycn.com

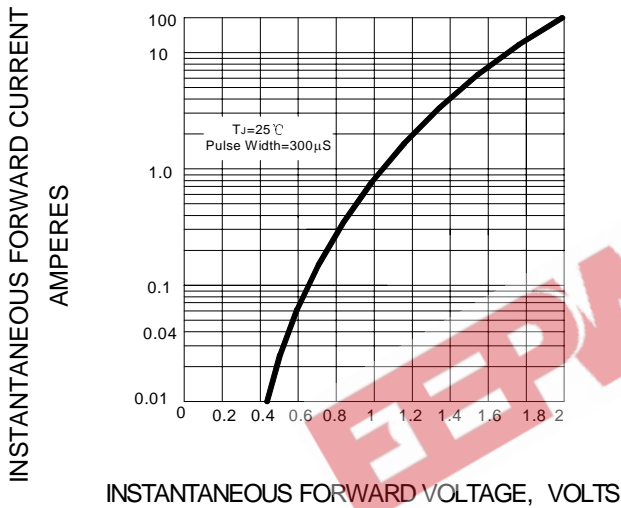
**FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



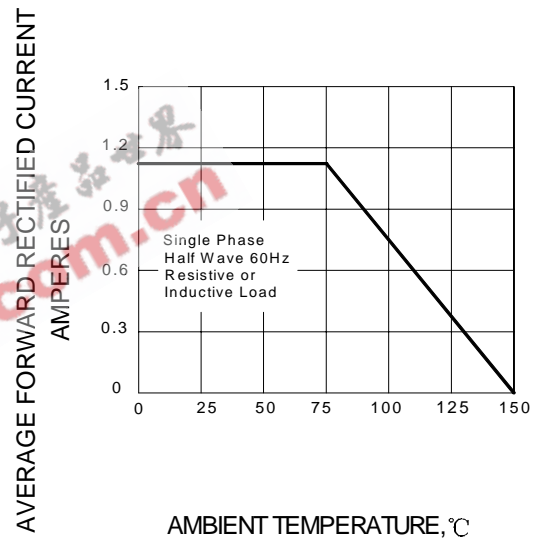
NOTES: 1. RISE TIME = 7ns MAX INPUT IMPEDANCE = 1MΩ, 22pF.  
 2. RISE TIME = 10ns MAX SOURCE IMPEDANCE = 50 Ω.

SET TIME BASE FOR 10/20 ns/cm

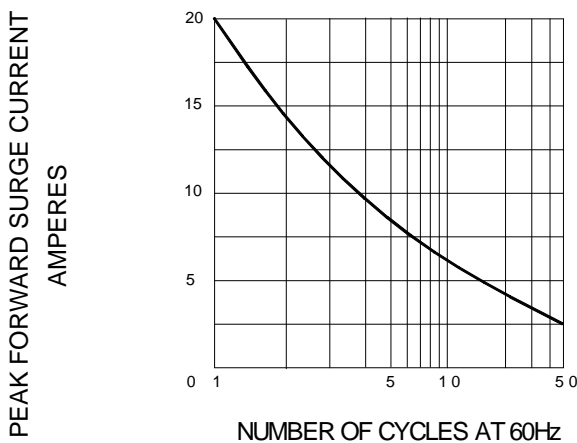
**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – FORWARD DERATING CURVE**



**FIG.2 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 – TYPICAL JUNCTION CAPACITANCE**

